

# Dual Channel Transmissive Optical Sensor with Phototransistor Output

#### Description

This device has a compact construction where the emitting-light sources and the detectors are located face-to-face on the same optical axes. The operating wavelength is 950 nm.

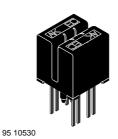
The detectors consists of a phototransistors. The distance of both channels is 2.66 mm.

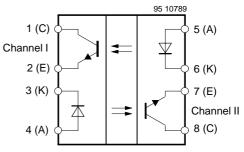
## Applications

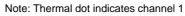
- Accurate position sensor for shaft encoder
- Detection of opaque material such as paper, IBM cards, magnetic tapes etc.
- Detection for motion direction

## Features

- Channel 1 to channel 2 distance 2.66 mm (optical center)
- Gap 1.5 mm
- Package height: 10 mm
- Plastic polycarbonate housing
- Aperture 0.2 mm for both channels
- Current Transfer Ratio (CTR) of typical 2%







#### **Order Instruction**

Ordering Code	Resolution (mm) / Aperture (mm)	Remarks
TCVT1300	/ 0.2	Dual channel

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# **Absolute Maximum Ratings**

#### Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V <sub>R</sub>	5	V
Forward current		١ <sub>F</sub>	50	mA
Forward surge current	$t_p \le 10 \ \mu s$	I <sub>FSM</sub>	3	А
Power dissipation	T <sub>amb</sub> ≤ 25°C	Pv	100	mW
Junction temperature		T <sub>j</sub>	100	°C

#### Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		Ι <sub>C</sub>	50	mA
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	100	mW
Junction temperature		Т <sub>і</sub>	100	°C

#### Coupler

Parameter	Test Conditions	Symbol	Value	Unit
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	200	mW
Operation temperature range		T <sub>amb</sub>	-25 to +85	°C
Storage temperature range		T <sub>stq</sub>	-25 to +100	°C
Soldering temperature	2 mm from case, $t \le 5 s$	T <sub>sd</sub>	260	°C



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#### **Electrical Characteristics** ( $T_{amb} = 25^{\circ}C$ )

Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I <sub>F</sub> = 30 mA	V <sub>F</sub>		1.20	1.3	V
Junction capacitance	$V_{R} = 0, f = 1 MHz$	Ci		50		рF

#### Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector emitter voltage	$I_{C} = 1 \text{ mA}$	V <sub>CEO</sub>	70			V
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>		10	200	nA

#### Coupler

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector current per channel	V <sub>CE</sub> = 10 V, I <sub>F</sub> = 30 mA	Ι <sub>C</sub>	400		1300	μΑ
Collector emitter saturation voltage	I <sub>F</sub> = 30 mA, I <sub>C</sub> = 0.1 mA	V <sub>CEsat</sub>			0.2	V
Crosstalk	V <sub>CE</sub> = 10 V, I <sub>F1</sub> = 0, I <sub>F2</sub> = 30 mA	I <sub>CX1</sub>			15	μΑ
	V <sub>CE</sub> = 10 V, I <sub>F1</sub> = 30 MA, I <sub>F2</sub> = 0	I <sub>CX2</sub>			15	μΑ
Phase angle	(see figure1)	Phi		90		o

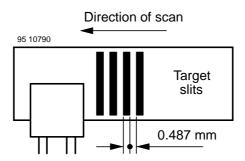


Figure 1. Test circuit for phase angle measurement



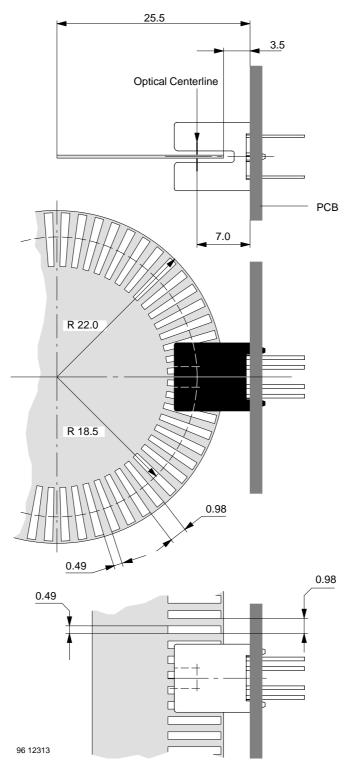


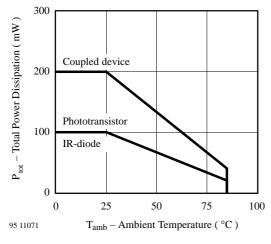
Figure 2.



# TCVT1300

#### **Vishay Telefunken**

# **Typical Characteristics** ( $T_{amb} = 25^{\circ}C$ , unless otherwise specified)





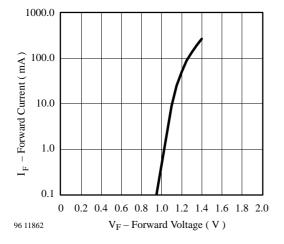
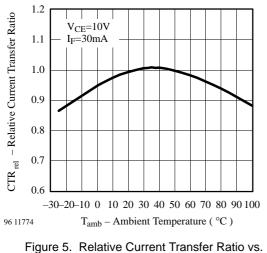


Figure 4. Forward Current vs. Forward Voltage



Ambient Temperature

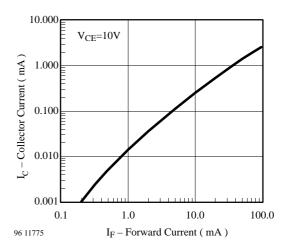


Figure 6. Collector Current vs. Forward Current

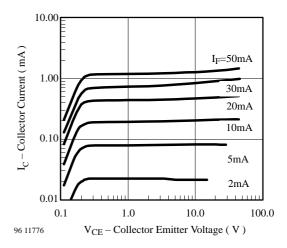


Figure 7. Collector Current vs. Collector Emitter Voltage

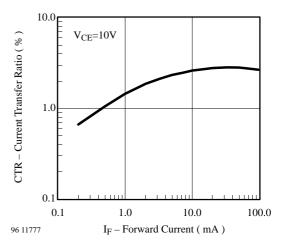


Figure 8. Current Transfer Ratio vs. Forward Current

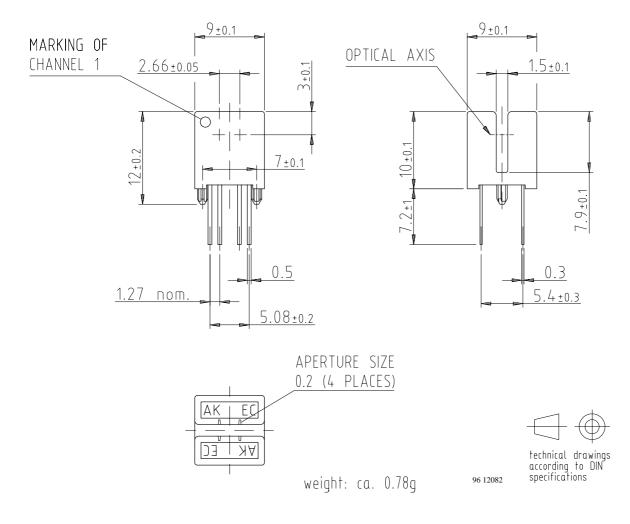
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# TCVT1300

#### Vishay Telefunken



# Dimensions of TCVT1300 in mm







#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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